NSN 5961-01-367-8097 Semiconductor Device Set - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
1.803 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Internal Junction Configuration:
Npn
Component Function Relationship:
Matched
Component Name And Quantity:
2 transistor
Mounting Method:
Threaded stud
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 15.0 breakdown voltage,
collector-to-base, emitter open
Current Rating Per Characteristic:
Between 7.50 amperes source cutoff current and 30.00 amperes source cutoff current
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0